Grain Boundary Structure and Dynamics: a tutorial

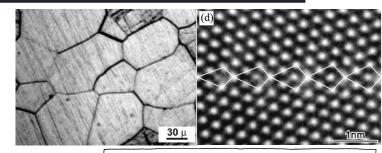
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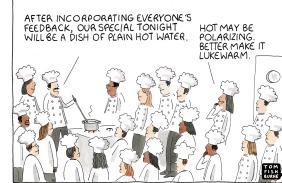
Departments of Materials Science and Engineering, Physics and Mechanical Engineering



About This Tutorial

- A "modern" view of grain boundaries
 - The study of GBs is ~1 century old
 - Like most fields, it advanced irregularly 1920s, 1960s, 1980s, 2000s
 - The past decade is another one of these times
- What this tutorial is about
 - GB structure, thermodynamic properties, and dynamics
 - How they are related
 - More ideas and concepts, than details
 - Focus on pure materials
- What this tutorial is NOT about
 - A survey or review of the field
 - A discussion of GB chemistry effects
- Who is this for?
 - Students new to the field
 - Scientists/engineers from peripheral areas or those looking for an update







About This Tutorial

Four lectures

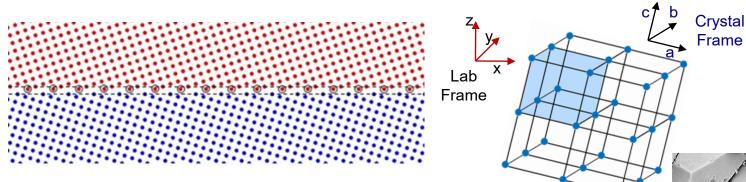
- GB basics, low angle GBs, structural unit model
- 2. GB thermodynamics, metastability, defects
- 3. GB dynamics
- 4. Continuum, microstructure issues

Lecture 4

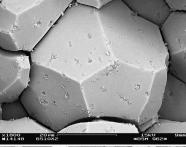
- references and reading material
- collaborators, acknowledgements

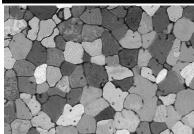
What is a Grain Boundary?

An interface across which grain <u>orientation</u> is discontinuous



- Grain boundaries in the "wild" (rather than domesticated, lab GBs)
 - Grains are finite-size domains of ~fixed crystal orientation
 - GBs are rarely flat
 - Microstructure:
 - Spatial arrangement of grains / crystal orientations
 - GB and GB triple-line networks
 - Manipulate microstructure through thermomechanical processing
 - Grain boundary engineering

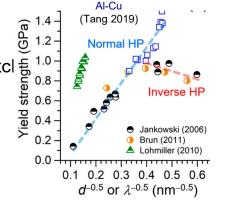


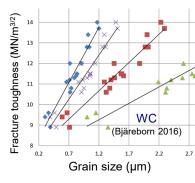


How Do GBs Affect Material Properties?

GBs and mechanical deformation

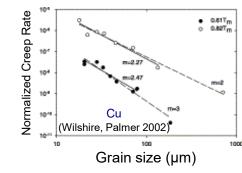
- Yield strength:
 - GBs block dislocations (smaller is stronger) Hall-Petcl
 - GBs slide (smaller is weaker) inverse Hall-Petch
- Fracture toughness
- Creep
- Fatigue (crack nucleation vs growth)
- ٠...





GBs and electrical/optical behavior

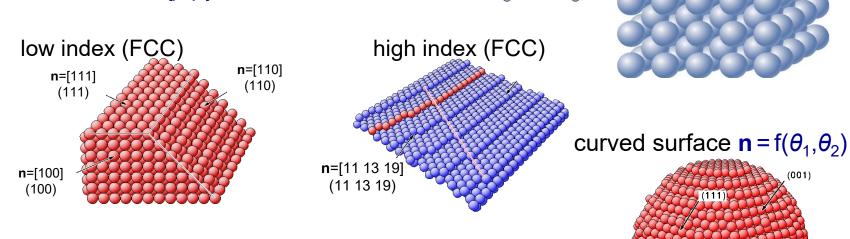
- Semiconductors: GBs are recombination sites
- Polycrystalline ceramic varistors: electrical breakdown at GBs
- Conductivity of superionic ceramics
 as grain size
 size
- In some semiconducting 2d materials, GBs are metallic
- Optical transparency: diffuse scattering 1 as grain size
- Solar cells: photoluminescence quantum yield/conversion efficiency ☆ as grain size ☆



Macroscopic Degrees of Freedom

Surface

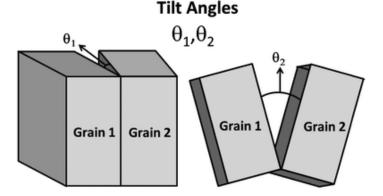
- Consider a body centered cubic (BCC) lattice
- Cleave it to create surfaces; choose normal n=⟨pqr⟩
- Different surfaces {pqr} have different structures

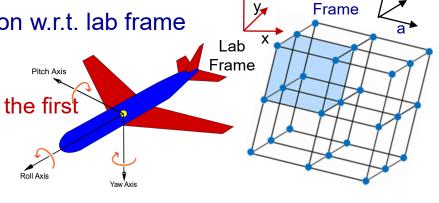


• Surface normal – 2 degrees of freedom $\mathbf{n} = \langle pqr \rangle = \mathbf{f}(\theta_1, \theta_2)$ because the normal is a unit vector (just direction): $p^2 + q^2 + r^2 = 1$

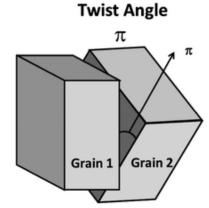
Macroscopic Degrees of Freedom

- Grain/crystal orientation
 - 3 angles/parameters set crystal orientation w.r.t. lab frame
 - GB \rightarrow 2 crystals:
 - Fix the orientation of the 1st : arbitrary
 - Fix the orientation of the 2nd relative to the first
 - 3 parameters/angles define misorientation
 - Many ways to do this
 - Here's a common one





Crystal

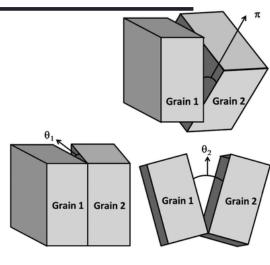


Another is to specify a rotation axis (2 parameters) and a rotation angle (1 parameter)

Common Terminology

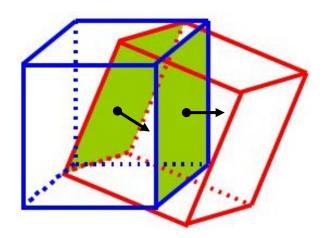
- Twist Grain Boundary
 - Rotation axis is perpendicular to GB plane
- Tilt Grain Boundary
 - Rotation axis lies within the GB plane
 - Symmetric tilt GB: GB is a mirror plane
- Mixed (tilt/twist) and Asymmetric Grain Boundary
 - Asymmetric: not symmetric/rotation axis in the GB plane
 - Mixed: rotation axis does lie within the GB plane
- Faceted Grain Boundary
 - Decomposition of GB into flat planes of other (more symmetric) GBs

Twist GB Symmetric Tilt GB Asymmetric Tilt GB Mixed GB Faceted GB Faceted GB



Macroscopic Degrees of Freedom

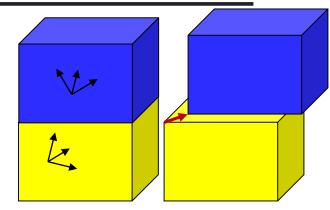
- Grain boundary bicrystallography variables
 - Once the misorientation between the grains is fixed (3 angles/parameters),
 choose the GB inclination like for a surface (2 angles/parameters)



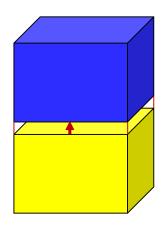
- GBs have 3+2=5 macroscopic, bicrystallographic degrees of freedom
 - These degrees of freedom are for *continuum* (structureless) grains
 - Does not depend on crystal structure or atomic structure of the GB

Microscopic Degrees of Freedom

- In-plane translations of one structureless grain with respect to another do not change anything
- But, when the grains have an atomic structure, inplane translations change GB structure & energy
- These lateral translations create 2 additional conservative degrees of freedom



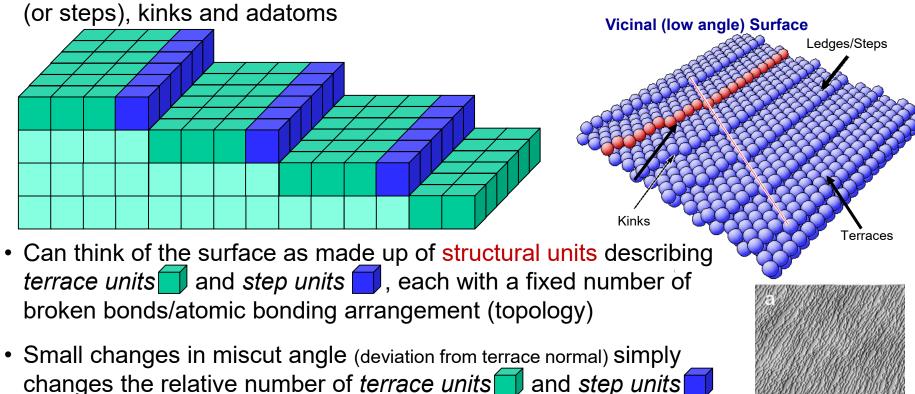
- We can also translate one grain with respect to the other in the direction normal to the GB plane
- This is a single, *non-conservative*, *microscopic* degree of freedom
- Requires the addition or removal of "extra atoms" at the GB plane



Surface Structure: a brief digression

per unit length/area

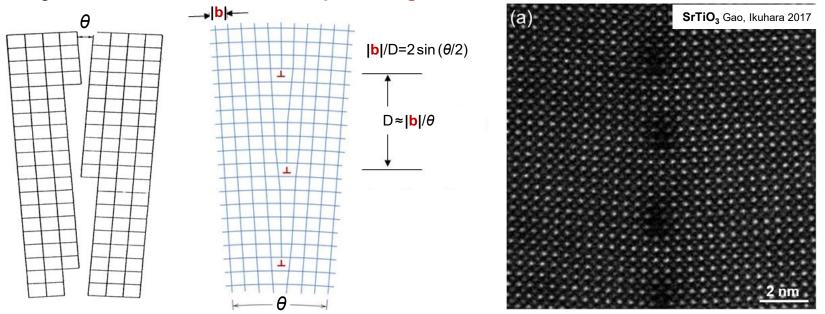
• A surface (at least at low T) can be viewed as an ensemble of terraces, ledges



Vicinal (001) Si Patella, 2004

Low Angle Grain Boundaries

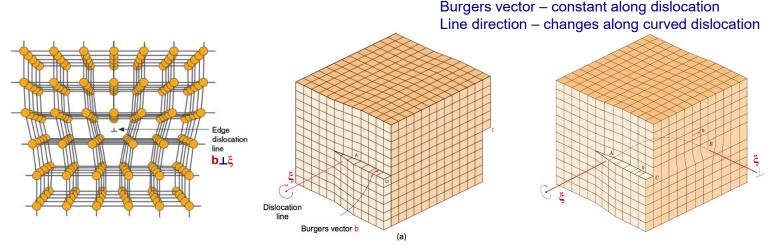
• Create a low angle grain boundary by joining two vicinal surfaces, each w/normal $\theta/2$ from the singular orientation: surface steps \rightarrow edge dislocations



- A low angle GBs can be thought of as a combination of two structural units:
 an edge dislocation core unit + a perfect crystal unit
- Perfect crystal units have the same bonding topology as the crystal but may be distorted
- Far from the GB, the crystals are perfect (undistorted)

Dislocations & Dislocation Arrays

Dislocations are characterized by a Burgers vector b and line direction ξ: edge b ± ξ, screw b||ξ



All (non-zero) components of the dislocation stress field:

$$\sigma \sim \frac{\mu b f(\theta)}{r}$$

Elastic energy per unit length:

$$\frac{E}{l} \sim \mu b^2 \ln \left(\frac{R}{r_c} \right) + e_c$$

where r_c and e_c are the dislocation core size and core energy (per unit length) – determined self-consistently

Dislocations & Dislocation Arrays

- Consider an array of edge dislocations as in the tilt GB

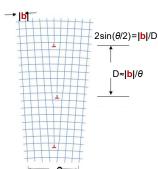
• The stress field of this array
$$\sigma_{xy} \cong \frac{2\pi\mu bx}{(1-v)}e^{-2\pi x/D}\cos\frac{2\pi y}{D}$$

- The stress field decays exponentially with |x| and is periodic in y
- The low angle GB (Read-Shockley) energy associated with the dislocation array is

$$\gamma \cong \frac{\mu b^2}{4\pi (1-v)D} \ln \left(\frac{e\alpha D}{2\pi b}\right) = \gamma_0 \theta \ln \left(\frac{e\theta_m}{\theta}\right)$$

where $\alpha = r_c/b$, $\theta_m = \alpha/2\pi$ and $\gamma_0 = \mu b/4\pi(1-v)$ – note that the dislocation core energies are buried in this expression by the appropriate choice of r_c and θ_m

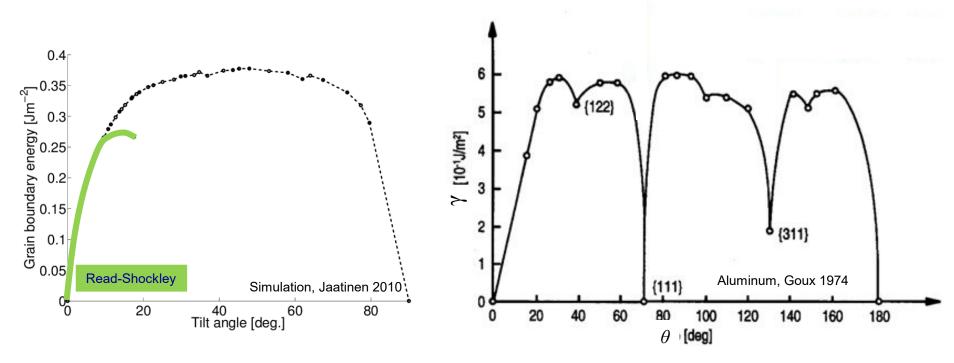
 This energy is finite although the strain energy associated with a single dislocation is infinite – this is because the array of dislocations screens the stress field of the individual dislocation (an infinite order multi-pole)



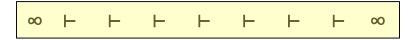


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Dislocations & Dislocation Arrays

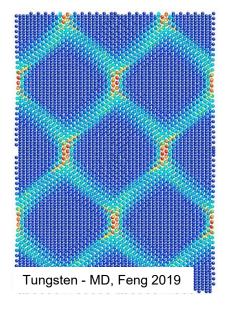


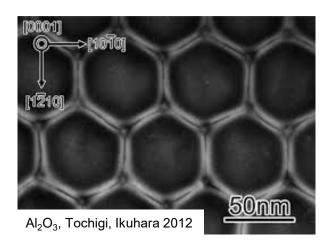
When dislocation spacing becomes comparable with dislocation core size, the dislocation model (Read-Shockley) for low angle GBs **fails**: the energy is dominated by the core NOT elasticity



Low Angle Grain Boundaries

- Previous discussion of low angle GBs focused on pure tilt GBs
- For pure twist GBs, the dislocations must have screw character; to cancel long-range stress field at least 2 sets of dislocations (**b**'s) are required
- For general low angle GBs (mixed, asymmetric) at least 3 sets of dislocations are required





Low Angle Grain Boundaries: conclusions

What are the key take away points from consideration of vicinal surfaces and LAGBs that we can generalize?

- 1. Planar interfaces can be described as an array of structural units; each with a unique atomic structure and bonding topology
- 2. The relative abundance of structural units depends on characteristic of the structural units (e.g., step height, Burgers vector) and macroscopic degrees of freedom (e.g., interface inclination, GB misorientation)
- 3. For vicinal surfaces/low angle GBs, the structural units correspond to terraces/perfect crystal AND steps/dislocations
- 4. For GBs, inclusion of elasticity for the dislocations is essential
- 5. Prediction of grain boundary energy requires description of the energy of the ideal structural units (core structure and bonding), long range elastic effects (elasticity), and the relative abundance/type of each structural unit (bicrystallography)

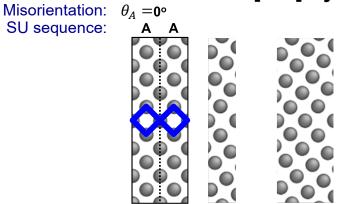
Multi-scale: bonding, atomic structure, continuum, crystallography

Structural Unit Model for Large Angle GBs

The structural unit model is based on the 3 central ideas: Bishop 1968 Sutton/Vitek

1. Describe GB structure as a 2D combination of structural units (SU); assign a letter to each (choice is not fixed, but must be consistent)

[100] Symmetric Tilt GB in a BCC Bicrystal



2. SU Combination:

SU size:

- GB with only 1 type of unit: delimiting GB
- GBs with misorientation between delimiting GB angles are combinations of the SU from the delimiting GBs: ratio of # of units $f(\theta)$

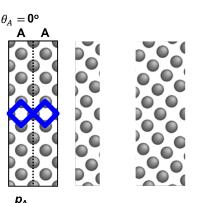
$$\frac{n_A}{n_C} = \frac{p_A}{p_C} \frac{\sin[(\theta_c - \theta)/2]}{\sin[(\theta - \theta_A)/2]}$$

 $\theta_R =$

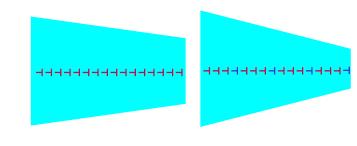
Structural Unit Model

3. SU Sequence:

- Consider the delimitting GB with SU "C": since θ is finite and there is only one SU, it must have an associated Burgers vector (with a component normal to the GB plane)
- Dislocations of same *b* repel one another, so minimize energy by maximizing their separation
- Consider $\theta = 18.92^{\circ}$: we can view the minority SUs "C" as dislocations on the delimiting "A" SU GB: these "C" SUs are secondary GB dislocations
- If there exists an n_A and n_C for a given θ that satisfies $n_A p_C \sin[(\theta \theta_A)/2] = n_C p_A \sin[(\theta_C \theta)/2]$, this GB is rational or periodic, if not, it is irrational (i.e., aperiodic)
- There is **nothing** physically special about a rational vs irrational (periodic or aperiodic GB)



$$\theta_C = \theta_B = 0$$



Grain Boundary Energy vs Misorientation

- Grain boundary energy: GB SU/core energy + elastic energy $\gamma(\theta) = \gamma^c(\theta) + \gamma^{el}(\theta)$
- The core energy depends on the geometry and energy of the delimiting GBs

$$\gamma^{c}(\theta) = \frac{1}{p} \left[n_{x} p_{x} \cos \left(\frac{\theta - \theta_{x}}{2} \right) \gamma_{x} + n_{y} p_{y} \cos \left(\frac{\theta_{y} - \theta}{2} \right) \gamma_{y} \right]$$

where the repeat distance p and number of units of each type are

$$p = n_x p_x \cos\left(\frac{\theta - \theta_x}{2}\right) + n_y p_y \cos\left(\frac{\theta_y - \theta}{2}\right) \qquad \frac{n_x}{n_y} = \frac{p_y \sin[(\theta_y - \theta)/2]}{\sin[(\theta - \theta_x)/2]}$$

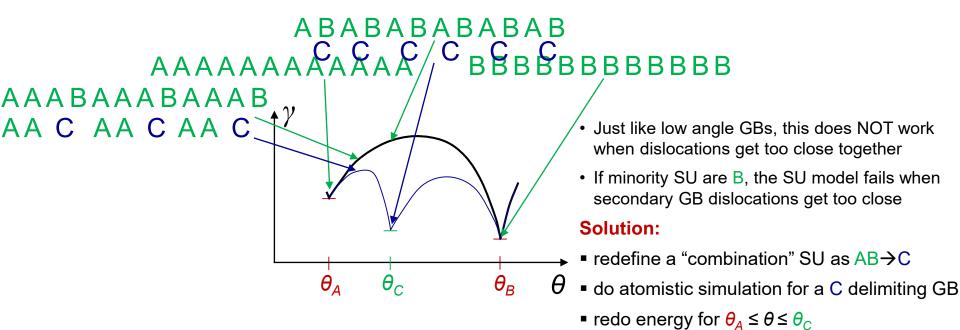
and γ_x and γ_y are the energies of the delimiting GBs

• The elastic energy is that of the secondary GB dislocation array $b_y = 2p_y \sin\left(\frac{\theta_y - \theta_x}{2}\right)$ $\gamma^{el}(\theta) = \frac{\mu b_y^2}{4\pi(1-\nu)D_y} \ln\frac{eD_y}{2\pi\pi r_y}$

or, more accurately (Li 1961)
$$\gamma^{el}(\theta) = \frac{\mu b_y^2}{4\pi(1-\nu)D_y} \left[\eta^* \coth \eta^* - \ln(2\sinh \eta^*) - \frac{\eta_0^2}{2} \operatorname{csch} \eta^{*2}\right]$$
, where $\eta_0 = \pi r_y/D_y$ and η^* is the solution to $\eta^* \tanh \eta^* = \eta_0^2$

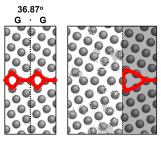
Grain Boundary Energy vs Misorientation

- The key question is "where do we get γ_x and γ_y (the energies of the delimiting GBs)?"
- Since they depend on detailed atomic structure and bonding resort to atomic-scale simulations



Iterative improvement → desired accuracy w/no or very little additional simulations

Grain Boundary Energy vs Misorientation



G=AB H=CB

Recursive application of SU model by combining AB →C, AAAB→AC,...

solid curve: γ^c (013) & (012) dashed curve: γ^c (013), (037), (012)

solid curve: γ (013) & (012) – no recursion

solid curve: γ (013) & (012) – 5 recursion steps dashed curve: γ (013), (037), (012)

